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RFMD's PowerSmart(TM) Wins Compound Semiconductor Industry's Most Innovative Device Award

GREENSBORO, N.C., March 29, 2011 (GLOBE NEWSWIRE) -- RF Micro Devices, Inc. (Nasdaq:RFMD), a global leader in the design and manufacture of high-performance radio frequency components and compound semiconductor technologies, today announced that *Compound Semiconductor* magazine has recognized the Company's PowerSmart™ power platform (RFRD6460) as the compound semiconductor industry's most innovative device of 2011. The award was presented on March 22, 2011, by *Compound Semiconductor* magazine during the 2011 CS Industry Awards in Frankfurt, Germany.

RFMD's revolutionary PowerSmart power platforms feature an RF Configurable Power Core™ that delivers multiband, multi mode coverage of all cellular communications modulation schemes, up to 4G LTE 64QAM. PowerSmart power platforms also include all necessary switching and signal conditioning functionality in a compact reference design, providing leading device manufacturers a single scalable source for the entire cellular front end.

The exceptional design flexibility of RFMD's PowerSmart power platforms enables designers of smartphones and tablets to eliminate months of development time and cover broader segments of the market with a single design, while saving considerably on size, current consumption and R&D cost, versus competitive offerings.

Bob Bruggeworth, president and CEO of RFMD, said, "We are extremely pleased that *Compound Semiconductor* magazine has recognized RFMD's PowerSmart as the compound semiconductor industry's most innovative device of 2011. RFMD is sharply focused on expanding our leadership in compound semiconductors into multiple markets, and we believe PowerSmart is at the forefront of a technology shift to converged front ends in multi-mode, multiband smartphones.

"In addition to our GaAs-based PowerSmart technology, RFMD's efforts in GaAs-based concentrated photovoltaics and GaN-based high power amplifiers are serving to extend the role of compound semiconductors in the world's fastest growing markets."

"*Compound Semiconductor* is proud of the CS Industry Awards and the overwhelming response from the compound semiconductor industry," said Richard Stevenson, Editor. "We feel it is important to highlight the technological achievements within the industry, such as RFMD's PowerSmart. These categories and products represent key areas of innovation in the chip manufacturing process."

RFMD recently commenced volume production shipments of the RFRD6460 PowerSmart power platform in support of the Samsung Galaxy S 2 family of 3G/4G smartphones and tablets and the LG Optimus 3D. The Company has a strong intellectual property position in support of PowerSmart, with multiple patent applications in process.

Compound Semiconductor magazine is the most authoritative and widest read title serving the compound semiconductor community worldwide.

About RFMD

RF Micro Devices, Inc. (Nasdaq:RFMD) is a global leader in the design and manufacture of high-performance semiconductor components. RFMD's products enable worldwide mobility, provide enhanced connectivity and support advanced functionality in the cellular handset, wireless infrastructure, wireless local area network (WLAN), CATV/broadband and aerospace and defense markets. RFMD is recognized for its diverse portfolio of semiconductor technologies and RF systems expertise and is a preferred supplier to the world's leading mobile device, customer premises and communications equipment providers.

Headquartered in Greensboro, N.C., RFMD is an ISO 9001- and ISO 14001-certified manufacturer with worldwide engineering, design, sales and service facilities. RFMD is traded on the NASDAQ Global Select Market under the symbol RFMD. For more information, please visit RFMD's web site at www.rfmd.com.

The RF Micro Devices, Inc. logo is available at <http://www.globenewswire.com/newsroom/prs/?pkgid=6436>

This press release includes "forward-looking statements" within the meaning of the safe harbor provisions of the Private Securities Litigation Reform Act of 1995. These forward-looking statements include, but are not limited to, statements about our plans, objectives, representations and contentions and are not historical facts and typically are identified by use of terms such as "may," "will," "should," "could," "expect," "plan," "anticipate," "believe," "estimate," "predict," "potential," "continue" and similar

words, although some forward-looking statements are expressed differently. You should be aware that the forward-looking statements included herein represent management's current judgment and expectations, but our actual results, events and performance could differ materially from those expressed or implied by forward-looking statements. We do not intend to update any of these forward-looking statements or publicly announce the results of any revisions to these forward-looking statements, other than as is required under the federal securities laws. RF Micro Devices' business is subject to numerous risks and uncertainties, including variability in operating results, risks associated with the impact of global macroeconomic and credit conditions on our business and the business of our suppliers and customers, our reliance on a few large customers for a substantial portion of our revenue, the rate of growth and development of wireless markets, our ability to bring new products to market, our reliance on inclusion in third party reference designs for a portion of our revenue, our ability to manage channel partner and customer relationships, risks associated with the operation of our wafer fabrication, molecular beam epitaxy, assembly and test and tape and reel facilities, our ability to complete acquisitions and integrate acquired companies, including the risk that we may not realize expected synergies from our business combinations, our ability to attract and retain skilled personnel and develop leaders, variability in production yields, raw material costs and availability, our ability to reduce costs and improve margins in response to declining average selling prices, our ability to adjust production capacity in a timely fashion in response to changes in demand for our products, dependence on gallium arsenide (GaAs) for the majority of our products, dependence on third parties, and substantial reliance on international sales and operations. These and other risks and uncertainties, which are described in more detail in RF Micro Devices' most recent Annual Report on Form 10-K and other reports and statements filed with the Securities and Exchange Commission, could cause actual results and developments to be materially different from those expressed or implied by any of these forward-looking statements.

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